

Vishay General Semiconductor

Surface-Mount TMBS[®] (Trench MOS Barrier Schottky) Rectifier



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	3 A				
V _{RRM}	150 V				
I _{FSM}	80 A				
V_F at I_F = 1.5 A (T_J = 125 °C)	0.55 V				
T _J max.	175 °C				
Package	DFN3820A				
Circuit configuration	Single				

FEATURES

- Low profile package - typical height of 0.88 mm Available
- Trench MOS Schottky technology
- Low power losses, high efficiency
- Low forward voltage drop
- COMPLIANT Meets MSL level 1, per J-STD-020, LF maximum HALOGEN peak of 260 °C FREE
- AEC-Q101 gualified available - Automotive ordering code; base P/NHM3
- Compatible to SMP (DO-220AA) package case outline
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

MECHANICAL DATA

Case: DFN3820A

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V3NM153	UNIT	
Device marking code		3MP		
Maximum repetitive peak reverse voltage	V _{RRM}	150	V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)} ⁽¹⁾	3	A	
	I _{F(AV)} ⁽²⁾	1.8	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	80	А	
Operating junction and storage temperature range	T _J ⁽³⁾	-40 to +175	°C	
Operating junction and storage temperature range	T _{STG}	-55 to +175	°C	

Notes

⁽¹⁾ Mounted on 10 mm x 10 mm copper pad area PCB

⁽²⁾ Free air, mounted on FR4 PCB, 2 oz., standard footprint

 $^{(3)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: dP_D/dT_J < 1/R_{b,IA}



RoHS





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ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage	I _F = 1.5 A	- T _J = 25 °C	V _E ⁽¹⁾	0.69	-	V	
	$I_F = 3.0 \text{ A}$			0.85	0.97		
	I _F = 1.5 A	– T _J = 125 °C	T 125 °C	VE	0.55	-	v
	$I_{F} = 3.0 \text{ A}$			0.62	0.68		
Reverse current	V 100 V	$V_{R} = 100 V \frac{T_{J} = 25 °C}{T_{J} = 125 °C}$	I _R (2)	0.0003	-		
	v _R = 100 v	T _J = 125 °C		0.5	-	mA	
	V _R = 150 V	T _J = 25 °C T _J = 125 °C		-	0.035	ША	
	v _R = 150 v	T _J = 125 °C		1.2	3		
Typical junction capacitance	4.0 V, 1 M⊦	4.0 V, 1 MHz		160	-	pF	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)					
PARAMETER	SYMBOL	TYP.	MAX.	UNIT	
Thermal registeres	R _{0JA} (1)(2)	135	169	°C/W	
Thermal resistance	R _{0JM} ⁽³⁾	5	6.3		

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Thermal resistance junction-to-ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint

⁽³⁾ Thermal resistance junction-to-mount to follow JEDEC 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V3NM153-M3/H	0.023	н	3500	7" diameter plastic tape and reel		
V3NM153-M3/I	0.023	I	14 000	13" diameter plastic tape and reel		
V3NM153HM3/H ⁽¹⁾	0.023	Н	3500	7" diameter plastic tape and reel		
V3NM153HM3/I ⁽¹⁾	0.023	l	14 000	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

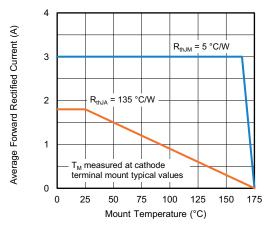


Fig. 1 - Maximum Forward Current Derating Curve

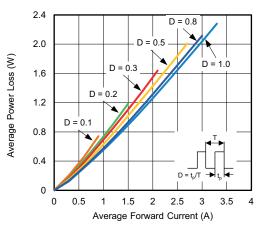


Fig. 2 - Forward Power Loss Characteristics

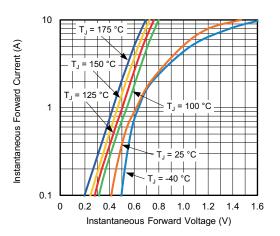


Fig. 3 - Typical Instantaneous Forward Characteristics

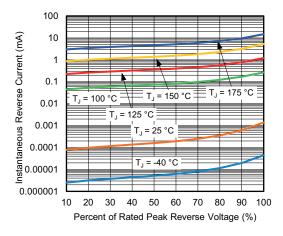


Fig. 4 - Typical Reverse Characteristics

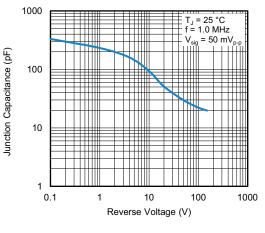


Fig. 5 - Typical Junction Capacitance

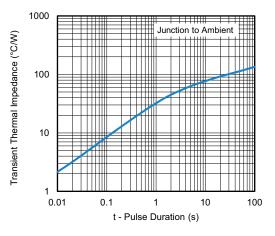


Fig. 6 - Typical Transient Thermal Impedance

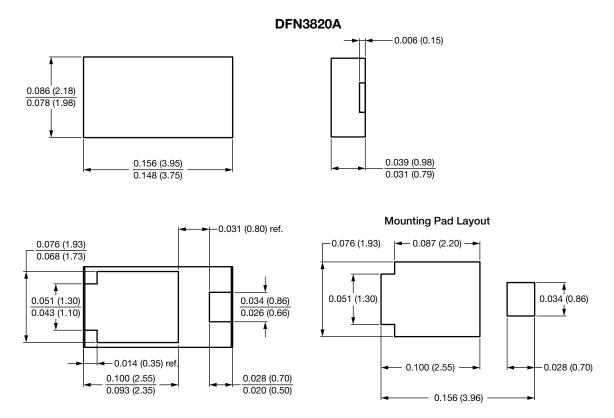
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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